



**Solid State Devices, Inc.**

14701 Firestone Blvd \* La Mirada, Ca 90638  
 Phone: (562) 404-4474 \* Fax: (562) 404-1773  
 ssdi@ssdi-power.com \* www.ssdi-power.com

**SSR40C100S1**  
**SSR40C120S1**

**40 A / 1200 V**  
**Schottky Silicon Carbide Rectifier**

**Designer's Data Sheet**

**Part Number / Ordering Information** <sup>1/</sup>

**SSR40C**

**Screening** <sup>2/</sup>         = Not Screened  
 TX = TX Level  
 TXV = TXV  
 S = S Level

**Package**    S1 = SMD1

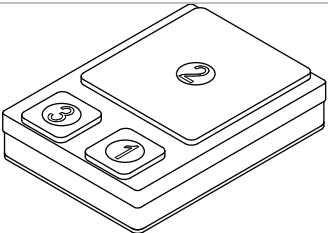
**Voltage**    100 = 1000 V  
                   120 = 1200 V

- FEATURES:**
- 1200 Volt Silicon Carbide Schottky Rectifier
  - Average Output Current 40 Amps
  - No Reverse Recovery
  - No Forward Recovery
  - No Switching Time Change Over Temperature
  - Small Package Size
  - TX, TXV, and Space Level Screening Available. <sup>2/</sup> Consult Factory.

<b>MAXIMUM RATINGS</b> <sup>3/</sup>		<b>Symbol</b>	<b>Value</b>	<b>Units</b>
<b>Peak Repetitive and Peak Reverse Voltage</b>	<b>SSR30C100S1</b> <b>SSR30C120S1</b>	$V_{RRM}$ $V_R$	1000 1200	<b>Volts</b>
<b>Average Rectified Forward Current</b> <sup>4/</sup> (Resistive Load, 60 Hz, Sine Wave)	Total	$I_O$	40	<b>Amps</b>
<b>Peak Surge Current</b> <sup>4/</sup> (8.3 ms Pulse, Half Sine Wave, $T_A = 25^\circ\text{C}$ )	Total	$I_{FSM}$	200	<b>Amps</b>
<b>Operating &amp; Storage Temperature</b>		$T_{OP} \& T_{stg}$	-55 to +250	<b>°C</b>
<b>Junction Temperature</b>		$T_J$	-55 to +250	<b>°C</b>
<b>Maximum Thermal Resistance</b> <sup>4/</sup> (Junction to Case)	Total	$R_{\theta JC}$	0.6	<b>°C/W</b>

**NOTES:**

<sup>1/</sup> For Ordering Information, Price, and Availability Contact Factory.  
<sup>2/</sup> Screened to MIL-PRF-19500.  
<sup>3/</sup> Unless Otherwise Specified, All Electrical Characteristics @25°C  
<sup>4/</sup> Terminal Pads 1 & 3 Must be connected together for testing and at the Board Level.



SMD1



**Solid State Devices, Inc.**

14701 Firestone Blvd \* La Mirada, Ca 90638  
 Phone: (562) 404-4474 \* Fax: (562) 404-1773  
 ssdi@ssdi-power.com \* www.ssdi-power.com

**SSR40C100S1**  
**SSR40C120S1**

ELECTRICAL CHARACTERISTICS <sup>3/ 4/</sup>		Symbol	Min	Typ	Max	Units
<b>Instantaneous Forward Voltage Drop</b> (T <sub>A</sub> =25°C, Pulse)	I <sub>F</sub> = 10 A	V <sub>F1</sub>	—	1.10	1.25	V <sub>DC</sub>
	I <sub>F</sub> = 20 A	V <sub>F2</sub>	—	1.20	1.35	
	I <sub>F</sub> = 30 A	V <sub>F3</sub>	—	1.35	1.50	
	I <sub>F</sub> = 40 A	V <sub>F4</sub>	—	1.45	1.65	
<b>Instantaneous Forward Voltage Drop</b> (T <sub>A</sub> =150°C, Pulse)	I <sub>F</sub> = 10 A	V <sub>F5</sub>	—	1.15	-	V <sub>DC</sub>
	I <sub>F</sub> = 20 A	V <sub>F6</sub>	—	1.27	1.50	
	I <sub>F</sub> = 30 A	V <sub>F7</sub>	—	1.73	-	
	I <sub>F</sub> = 40 A	V <sub>F8</sub>	—	1.97	2.30	
<b>Instantaneous Forward Voltage Drop</b> (T <sub>A</sub> =-55°C, Pulsed)	I <sub>F</sub> = 10 A	V <sub>F9</sub>	—	1.10	-	V <sub>DC</sub>
	I <sub>F</sub> = 20 A	V <sub>F10</sub>	—	1.15	1.30	
	I <sub>F</sub> = 30 A	V <sub>F11</sub>	—	1.25	-	
	I <sub>F</sub> = 40 A	V <sub>F12</sub>	—	1.40	1.60	
<b>Reverse Leakage Current</b> (Rated V <sub>R</sub> , Pulsed)	T <sub>A</sub> = 25°C	I <sub>R1</sub>	—	30	100	μA
	T <sub>A</sub> = 125°C	I <sub>R2</sub>		40	-	
	T <sub>A</sub> = 150°C	I <sub>R3</sub>		50	500	
	T <sub>A</sub> = 175°C	I <sub>R4</sub>		60	-	
<b>Junction Capacitance</b> (V <sub>R</sub> = 10V, f = 1MHz, T <sub>A</sub> = 25°C)		C <sub>J</sub>	—	1500	2000	pF

**NOTES:**  
 \* Pulse Test: Pulse Width = 300 usec, Duty Cycle = 2%  
 1/ For Ordering Information, Price, and Availability Contact Factory.  
 2/ Screened to MIL-PRF-19500.  
 3/ Unless Otherwise Specified, All Electrical Characteristics @25°C  
 4/ Terminal Pads 1 & 3 must be connected together for testing and at the Board Level.

**Available Part Numbers:**  
**SSR40C100S1**  
**SSR40C120S1**

PIN ASSIGNMENT			
Package	Pin 1	Pin 2	Pin 3
SMD1	Anode	Cathode	Anode

